

Answer all Questions.

All Questions carry equal marks

Exam Duration 3 hour

No books or papers are allowed.

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Question 1

- a) Discuss the merits of implementing digital circuits in FPGAs
b) Implement function F1 using 2, 3, and 4 variable LUT and select optimum implementation according to Table 1
 $F(A,B,C,D,E,F,G,H) = ABC + A'BE + BCFGH + CD'FH + AC'F'G$

Table 1

Table Size, variables	Delay, ns	Area, mm ²
2	2	7
3	3	11
4	4	26

Question 2

Design the *fastest circuit* to implement the following function:

$$F = X Y - Z$$

where X and Y are 4-bit unsigned binary number and Z is 4-bit signed (2's complement) binary number:

$$\mathbf{X} = x_3 x_2 x_1 x_0, \quad \mathbf{Y} = y_3 y_2 y_1 y_0, \quad \mathbf{Z} = z_3 z_2 z_1 z_0$$

Identify the critical path and give estimated time in terms of full adders delay, T_f .

Question 3

Design a 4-bit ring counter with the following output: 0001, 1000, 0100, 0010, 0001, 1000 and so on... Start with a state diagram and follow sequential circuit design procedure. Use D Flip Flop for your implementation.

Question 4

- Determine the maximum speed of operation at typical conditions for the serial multiplier control circuit shown in Fig. 1, taking into consideration the fan-out loading only. Timing parameters for all components are listed Table.2.
- At the maximum speed of operation, determine the slack time for the setup time and hold time at the D-input of Flip-Flop U6.
- After the realization of the circuit on a silicon chip, a delay of 3.5ns has been introduced at the clock of U1 F/F relative to other clock signals. Calculate the maximum speed of operation.

Note: All inputs: Begin, Qo and Co have arrival time at $t = -\infty$.

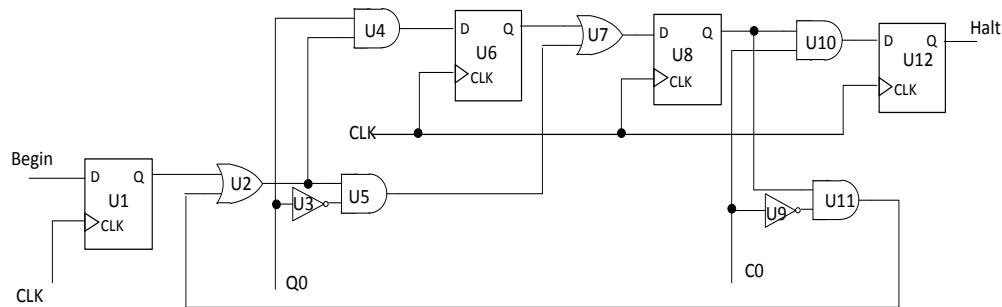


Fig. 1

Table 2

Component	Tp (ns)	Input Loading(UL)	K1 (ns/UL)
Inverter	1.5	1	0.2
2 input AND	2.0	1.5	0.25
2 input OR	2.5	1.5	0.25
D-F/F*	3.0	1 (all inputs)	0.2

* $t_{su}=1.5ns$, $t_h=0.5ns$

Question 5

The circuit shown in Fig. 2 operates in the military temperature range of -55°C to 125°C with a supply voltage fluctuation of +/- 10%. The device is packaged in a flat pack with a thermal resistance of 30°C/W and dissipates power of 3W. The input signals, A, B and C arrive at t = 0.

The timing characteristics of each of the components of the circuit are shown in Table 3.

- Determine the worst case arrival time of signal A at point D
- Determine the maximum clock frequency of operation to guarantee reliable operation.

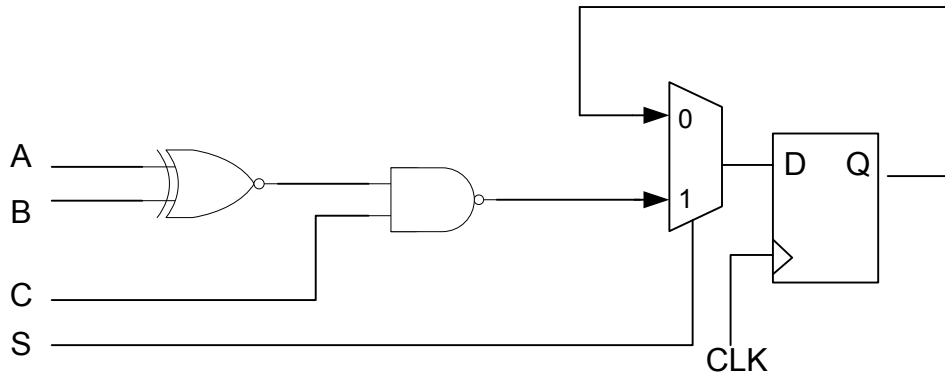


Fig. 2

Table 3- Timing Characteristics of Logic Gates

Gate	Intrinsic delay T_p (ns)	Input Loading (UL)	K1 (ns/UL)
2 input NAND	0.25	2	0.03
2 input XNOR	0.4	2	0.05
2 input Mux	0.3	1.5	0.1
D Flip-Flop (TCQ) $T_{su}=0.2ns, t_h=0.1ns$	0.5	2	0.07

Equations

$$T_d = (T_p + K_1 \sum N_i + K_2 M_L) \times K^* \quad K^* = K_T \times K_V \times K_P$$

$$K_T = \left(\frac{T_2}{T_1} \right)^M, \quad t_j = t_a + \Theta_{ja} \times P_d, \quad M = -1.5$$

$$K_V = \frac{1}{1 + 0.01 \times f_s} \quad K_P = 1 + 0.01 \times f_p$$

Question 6

- a) Write a VHDL Code that represent the following circuit given in Fig. 3

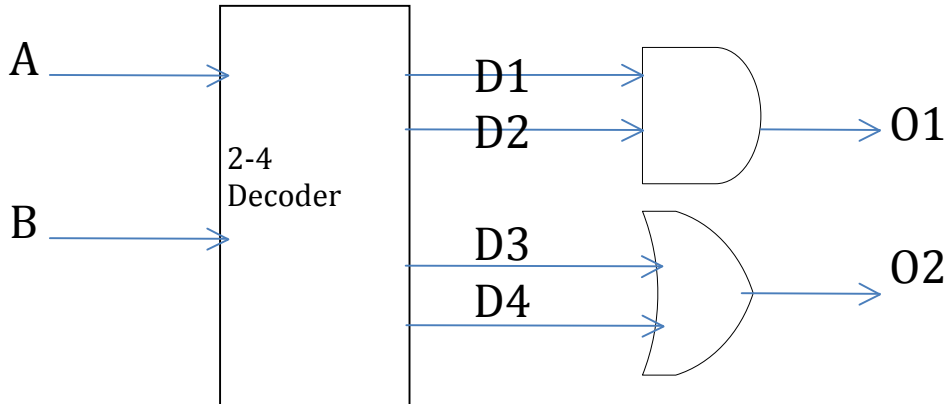


Fig. 3

- b) Find the Syntax and Semantic errors in the code below:

```

entity H_A_Con is ..... L1
port (X,Y:Istd_logic;.....L2
      SUM,CARRY:out std_logic);.....L3
end Half_A_Con; .....L4
architecture behavioral of H_A_Behav is .....L5
--signal X,Y:integer; .....L6
-signal SUM,CARRY:bit; .....L7
begin
  process (X,Y); .....L8
  variable Z:integer; .....L9
  begin .....L10
    SUM<='0'; .....L11
    CARRY<='0'; .....L12
    Z:=X+Y; .....L13
    if (Z=1) then SUM<='1'; .....L14
  elsif (Z=2) then CARRY<='1'; .....L15
    end ; .....L17
  end process; .....L18
end behavioral; .....L19

```